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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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2SJ528(L), 2SJ528(S)

Silicon P Channel MOS FET

REJ03G0878-0300

(Previous: ADE-208-641A)

Rev.3.00 Sep 07, 2005

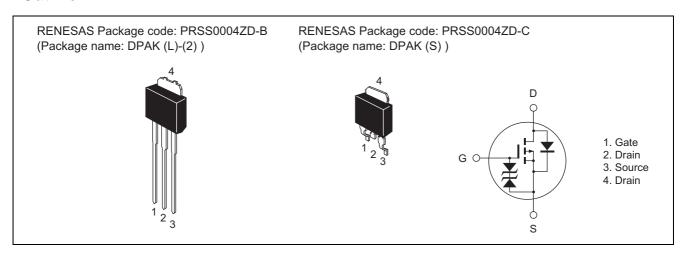
Description

High speed power switching

Features

- Low on-resistance $R_{DS (on)} = 0.17 \Omega \text{ typ.}$
- 4 V gate drive devices
- High speed switching

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Value | Unit |
|---|-------------------------------|-------------|------|
| Drain to source voltage | V _{DSS} | -60 | V |
| Gate to source voltage | V_{GSS} | ±20 | V |
| Drain current | I _D | -7 | Α |
| Drain peak current | I _{D (pulse)} Note 1 | -28 | Α |
| Body to drain diode reverse drain current | I _{DR} | -7 | Α |
| Avalanche current | I _{AP} Note 3 | -7 | Α |
| Avalanche energy | E _{AR} Note 3 | 4.2 | mJ |
| Channel dissipation | Pch Note 2 | 20 | W |
| Channel temperature | Tch | 150 | °C |
| Storage temperature | Tstg | −55 to +150 | °C |

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

3. Value at Tch = 25°C, Rg \geq 50 Ω

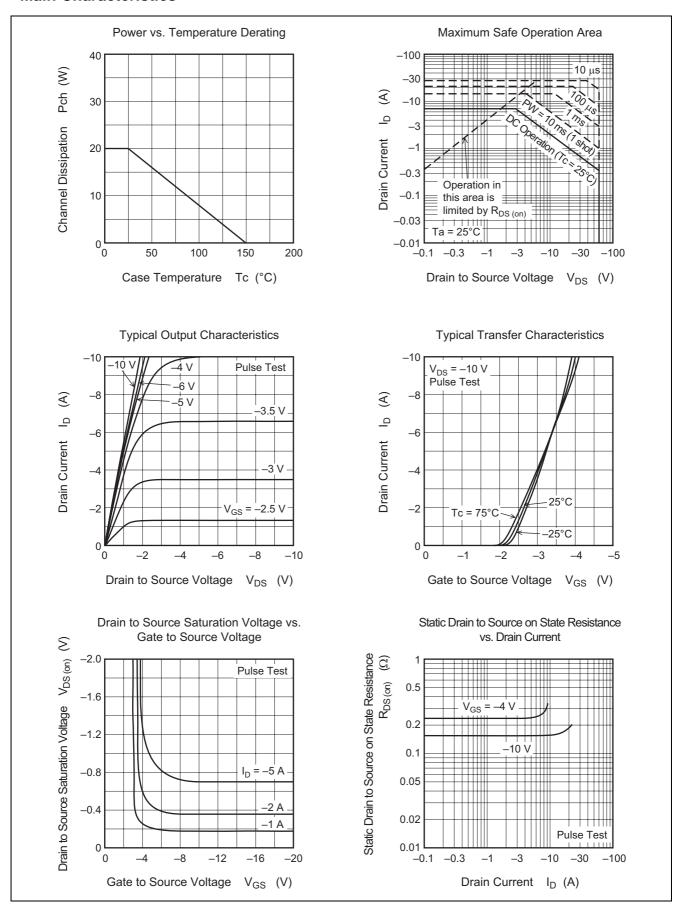
Electrical Characteristics

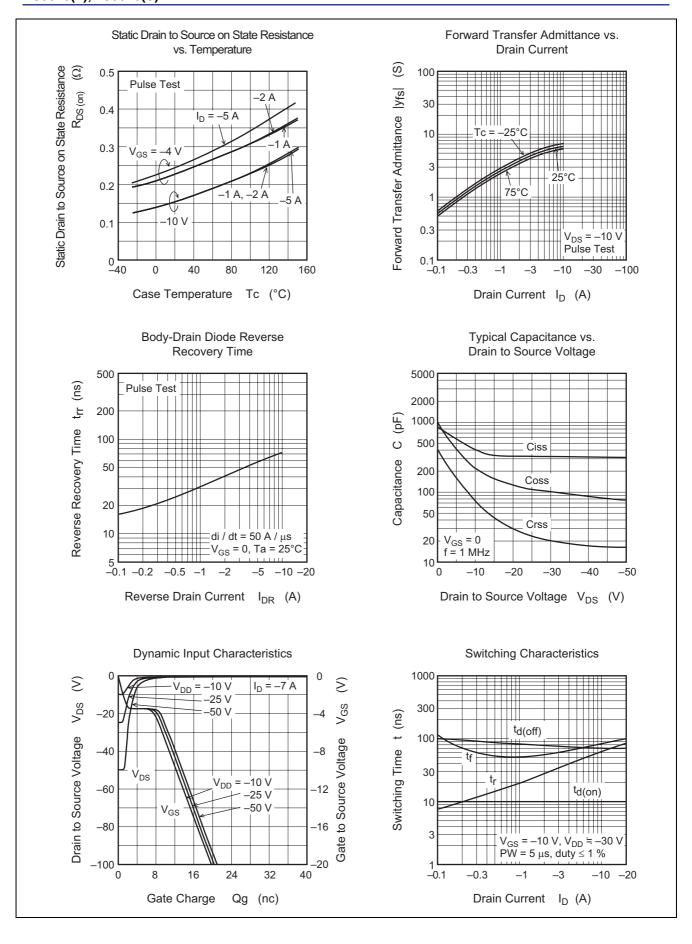
 $(Ta = 25^{\circ}C)$

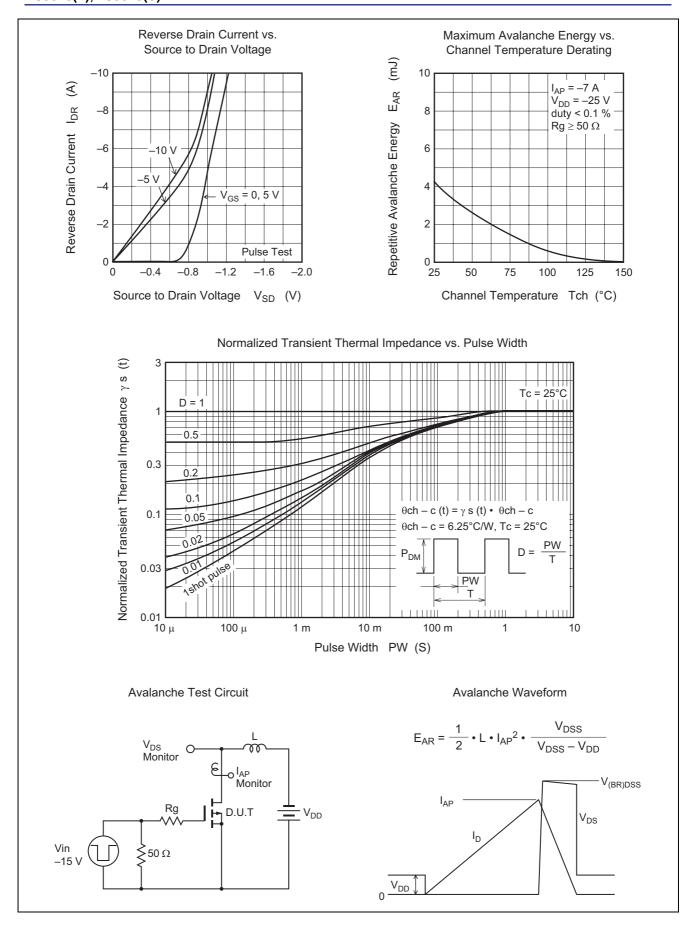
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|--|-----------------------|------|------|------|------|--|
| Drain to source breakdown voltage | V _{(BR) DSS} | -60 | _ | _ | V | $I_D = -10 \text{ mA}, V_{GS} = 0$ |
| Gate to source breakdown voltage | V _{(BR) GSS} | ±20 | _ | _ | V | $I_G = \pm 100 \ \mu A, \ V_{DS} = 0$ |
| Zero gate voltage drain current | I _{DSS} | _ | _ | -10 | μΑ | $V_{DS} = -60 \text{ V}, V_{GS} = 0$ |
| Gate to source leak current | I _{GSS} | _ | _ | ±10 | μΑ | $V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$ |
| Gate to source cutoff voltage | V _{GS (off)} | -1.0 | _ | -2.0 | V | $I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$ |
| Static drain to source on state resistance | R _{DS (on)} | _ | 0.17 | 0.22 | Ω | $I_D = -4 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 4}}$ |
| Static drain to source on state resistance | R _{DS (on)} | _ | 0.24 | 0.37 | Ω | $I_D = -4 \text{ A}, V_{GS} = -4 \text{ V}^{\text{Note 4}}$ |
| Forward transfer admittance | y _{fs} | 3.0 | 5.0 | _ | S | $I_D = -4 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note 4}}$ |
| Input capacitance | Ciss | _ | 400 | _ | pF | $V_{DS} = -10 \text{ V}$ |
| Output capacitance | Coss | _ | 220 | _ | pF | $V_{GS} = 0$ |
| Reverse transfer capacitance | Crss | _ | 75 | _ | pF | f = 1 MHz |
| Turn-on delay time | t _{d (on)} | _ | 10 | _ | ns | V _{GS} = -10 V |
| Rise time | t _r | _ | 40 | _ | ns | $I_D = -4 A$ |
| Turn-off delay time | t _{d (off)} | _ | 75 | _ | ns | $R_L = 7.5 \Omega$ |
| Fall time | t _f | _ | 65 | _ | ns | |
| Body to drain diode forward voltage | V_{DF} | _ | -1.1 | _ | V | $I_F = -7 \text{ A}, V_{GS} = 0$ |
| Body to drain diode reverse recovery time | t _{rr} | _ | 65 | _ | ns | $I_F = -7 \text{ A}, V_{GS} = 0$ |
| | | | | | | di _F /dt = 50 A/μs |

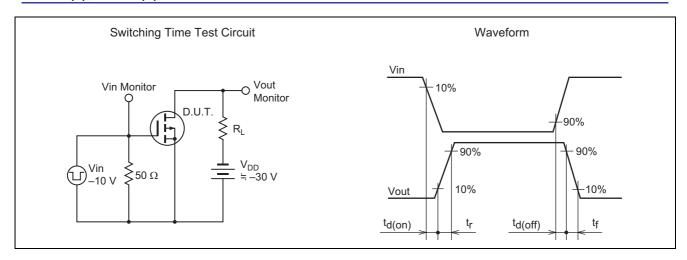
Note: 4. Pulse test

Main Characteristics

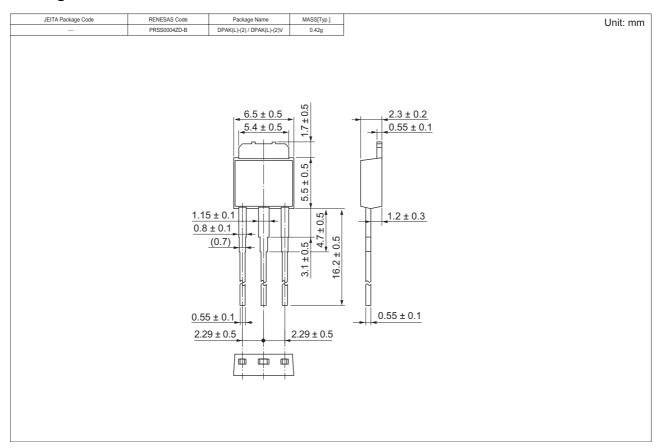


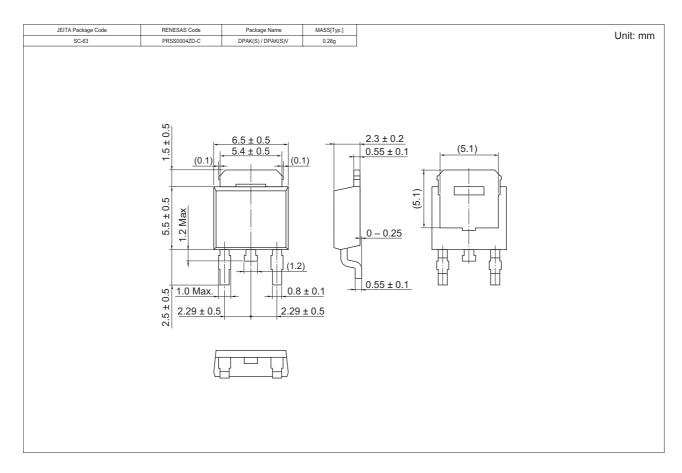






Package Dimensions





Ordering Information

| Part Name | Quantity | Shipping Container |
|-------------|----------|--------------------|
| 2SJ528L-E | 3200 pcs | Box (Sack) |
| 2SJ528STL-E | 3000 pcs | Taping |

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